

SCES613I-OCTOBER 2004-REVISED MAY 2010

SINGLE-SUPPLY VOLTAGE-LEVEL TRANSLATOR WITH NINE CONFIGURABLE GATE LOGIC FUNCTIONS

Check for Samples: SN74AUP1T97

FEATURES

- Available in the Texas Instruments NanoStar™ Packages
- Single-Supply Voltage Translator
- 1.8 V to 3.3 V (at $V_{CC} = 3.3$ V)
- 2.5 V to 3.3 V (at $V_{CC} = 3.3$ V) •
- 1.8 V to 2.5 V (at $V_{CC} = 2.5$ V)
- 3.3 V to 2.5 V (at $V_{CC} = 2.5$ V)
- **Nine Configurable Gate Logic Functions**
- Schmitt-Trigger Inputs Reject Input Noise and **Provide Better Output Signal Integrity**
- Ioff Supports Partial-Power-Down Mode With Low Leakage Current (0.5 µA)
- Very Low Static and Dynamic Power • Consumption
- Pb-Free Packages Available: SON (DRY or ٠ DSF), SOT-23 (DBV), SC-70 (DCK), and NanoStar WCSP
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Performance Tested Per JESD 22**
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Related Devices: SN74AUP1T98, SN74AUP1T57, and SN74AUP1T58

DESCRIPTION/ORDERING INFORMATION

AUP technology is the industry's lowest-power logic technology designed for use in battery-operated or battery backed-up equipment. The SN74AUP1T97 is designed for logic-level translation applications with input switching levels that accept 1.8-V LVCMOS signals, while operating from either a single 3.3-V or 2.5-V V_{CC} supply.

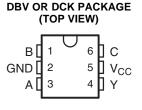
The wide V_{CC} range of 2.3 V to 3.6 V allows the possibility of battery voltage drop during system operation and ensures normal operation between this range.

Schmitt-trigger inputs (ΔV_T = 210 mV between positive and negative input transitions) offer improved noise immunity during switching transitions, which is especially useful on analog mixed-mode designs. Schmitt-trigger inputs reject input noise, ensure integrity of output signals, and allow for slow input signal transition.

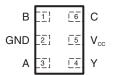
The SN74AUP1T97 can be easily configured to perform a required gate function by connecting A, B, and C inputs to V_{CC} or ground (see Function Selection table). Up to nine commonly used logic gate functions can be performed.



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DRY OR DSF PACKAGE (TOP VIEW)



YFP OR YZP PACKAGE (TOP VIEW)

			1
В	(Á1) 1	6 (Áz)	С
GND	(B)¹ 2	5 🔊	V _{CC}
B GND A	(ćj) 3	4 (ćz)	Y



SCES613I-OCTOBER 2004-REVISED MAY 2010

 I_{off} is a feature that allows for powered-down conditions ($V_{CC} = 0$ V) and is important in portable and mobile applications. When $V_{CC} = 0$ V, signals in the range from 0 V to 3.6 V can be applied to the inputs and outputs of the device. No damage occurs to the device under these conditions.

The SN74AUP1T97 is designed with optimized current-drive capability of 4 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

NanoStar package technology is a major breakthrough in IC packaging concepts, using the die as the package.

OPDEDING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾						
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1T97YZPR	TH_						
	NanoStar™– WCSP (DSBGA)0.23-mm Large Bump – YFPReel of 3000		SN74AUP1T97YFPR	TH_						
–40°C to 85°C	QFN – DRY	Reel of 5000	SN74AUP1T97DRYR	ТН						
	uQFN – DSF	Reel of 5000	SN74AUP1T97DSFR	тн						
	SOT (SOT-23) – DBV	Reel of 3000	SN74AUP1T97DBVR	HT4_						
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP1T97DCKR	TH_						

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

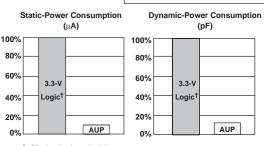
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, ● = Pb-free).

FUNCTION SELECTION TABLE						
LOGIC FUNCTION	FIGURE NO.					
2-to-1 data selector	5					
2-input AND gate	6					
2-input OR gate with one inverted input	7					
2-input NAND gate with one inverted input	7					
2-input AND gate with one inverted input	8					
2-input NOR gate with one inverted input	8					
2-input OR gate	9					
Inverter	10					
Noninverted buffer	11					

FUNCTION SELECTION TABLE



[†] Single, dual, and triple gates



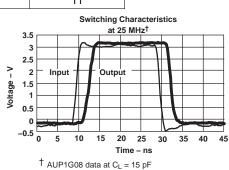


Figure 2. Excellent Signal Integrity

2



SCES613I-OCTOBER 2004-REVISED MAY 2010

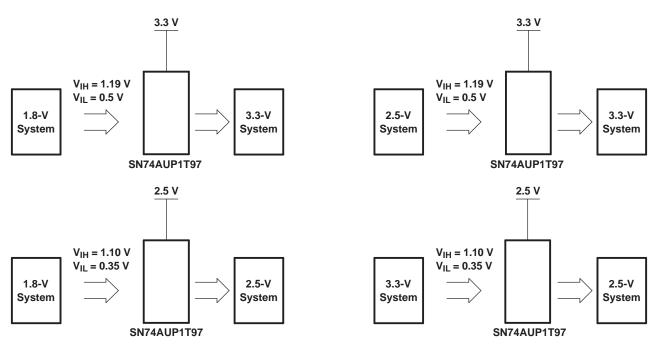


Figure 3. Possible Voltage-Translation Combinations

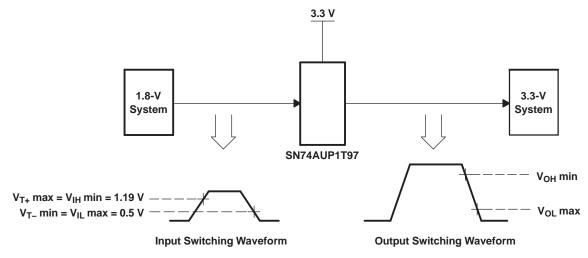


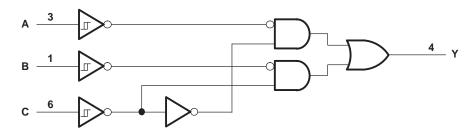
Figure 4. Switching Thresholds for 1.8-V to 3.3-V Translation



SCES613I-OCTOBER 2004-REVISED MAY 2010

	FUNCTION TABLE									
	INPUTS		OUTPUT							
С	В	Α	Y							
L	L	L	L							
L	L	н	L							
L	н	L	н							
L	н	н	н							
Н	L	L	L							
Н	L	Н	н							
Н	н	L	L							
Н	Н	Н	Н							

LOGIC DIAGRAM (POSITIVE LOGIC)



LOGIC CONFIGURATIONS

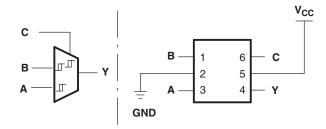


Figure 5. 157: 2-to-1 Data Selector/MUX When C is L, Y = B When C is H, Y = A

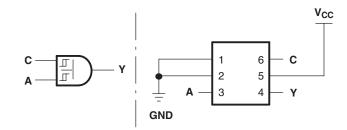


Figure 6. 08: 2-Input AND Gate



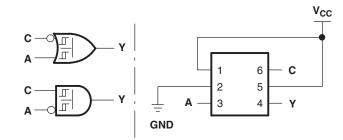


Figure 7. 14+32/14+00: 2-Input OR/NAND Gate With One Inverted Input

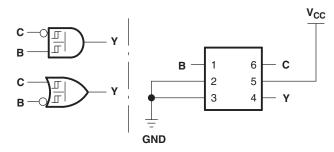


Figure 8. 14+08/14+02: 2-Input AND/NOR Gate With One Inverted Input

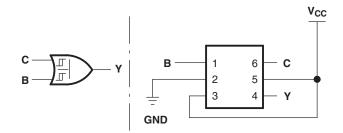
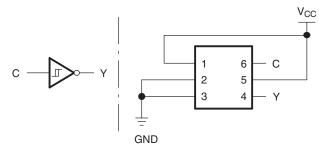
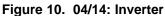


Figure 9. 32: 2-Input OR Gate







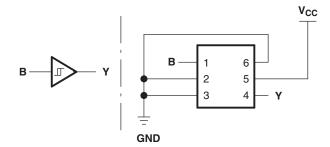


Figure 11. 17/34: Noninverted Buffer



SCES613I-OCTOBER 2004-REVISED MAY 2010

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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾		-0.5	4.6	V
Vo	Output voltage range in the high or low state	Output voltage range in the high or low state ⁽²⁾		V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V ₀ < 0		-50	mA
lo	Continuous output current		±20	mA	
	Continuous current through V_{CC} or GND			±50	mA
		DBV package		165	
		DCK package		259	
0	Declarge the second increase (3)	DRY package		340	0000
θ_{JA}	Package thermal impedance ⁽³⁾	DSF package		300	°C/W
		YFP package		123	
		YZP package		123	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2.3	3.6	V
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V_{CC}	V
	Llich lovel output ourrent	$V_{CC} = 2.3 V$		-3.1	~ ^
IOH	High-level output current	$V_{CC} = 3 V$		-4	mA
		V _{CC} = 2.3 V		3.1	~ ^
OL	Low-level output current	$V_{CC} = 3 V$		4	mA
T _A	Operating free-air temperature		-40	85	°C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report *Implications* of Slow or Floating CMOS Inputs, literature number SCBA004.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	T _A =	= 25°C	T _A = -40 to 85°0		UNIT	
			MIN	TYP MAX	MIN	MAX		
V _{T+}		2.3 V to 2.7 V	0.6	1.1	0.6	1.1		
Positive-going input threshold voltage		3 V to 3.6 V	0.75	1.16	0.75	1.19	V	
V _{T-}		2.3 V to 2.7 V	0.35	0.6	0.35	0.6		
Negative-going input threshold voltage		3 V to 3.6 V	0.5	0.85	0.5	0.85	V	
ΔV_T		2.3 V to 2.7 V	0.23	0.6	0.1	0.6		
Hysteresis (V _{T+} – V _{T–})		3 V to 3.6 V	0.25	0.56	0.15	0.56	V	
V _{OH}	I _{OH} = -20 μA	2.3 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1			
	$I_{OH} = -2.3 \text{ mA}$	0.014	2.05		1.97			
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85		V	
	I _{OH} = -2.7 mA	21/	2.72		2.67			
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55			
	I _{OL} = 20 μA	2.3 V to 3.6 V		0.1		0.1		
	I _{OL} = 2.3 mA	2.3 V		0.31		0.33	I	
V _{OL}	I _{OL} = 3.1 mA	2.3 V		0.44		0.45	V	
	I _{OL} = 2.7 mA	3 V		0.31		0.33		
	$I_{OL} = 4 \text{ mA}$	3 V		0.44		0.45		
II All inputs	$V_1 = 3.6 \text{ V or GND}$	0 V to 3.6 V		0.1		0.5	μA	
l _{off}	V_1 or $V_0 = 0$ V to 3.6 V	0 V		0.1		0.5	μA	
ΔI _{off}	$V_1 \text{ or } V_0 = 3.6 \text{ V}$	0 V to 0.2 V		0.2		0.5	μA	
I _{CC}	$V_1 = 3.6 \text{ V or GND}, I_0 = 0$	2.3 V to 3.6 V		0.5		0.9	μA	
Alee	One input at 0.3 V or 1.1 V, Other inputs at 0 or V _{CC} , $I_0 = 0$	2.3 V to 2.7 V				4	μA	
ΔI _{CC}	One input at 0.45 V or 1.2 V, Other inputs at 0 or V _{CC} , $I_0 = 0$	3 V to 3.6 V				12		
C _i	$V_I = V_{CC}$ or GND	3.3 V		1.5			pF	
Co	$V_0 = V_{CC}$ or GND	3.3 V		3			pF	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$, $V_I = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	PARAMETER FROM TO CL	т,	ק = 25°C		T _A = to 85	UNIT			
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	
			5 pF	1.8	2.3	2.9	0.5	6.8	
		v	10 pF	2.3	2.8	3.4	1	7.9	
t _{pd}	A, B, or C	Y	15 pF	2.6	3.1	3.8	1	8.7	ns
			30 pF	3.8	4.4	5.1	1.5	10.8	

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SCES613I-OCTOBER 2004-REVISED MAY 2010

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$, $V_1 = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER FROM TO CL	CL	T _A = 25°C			T _A = to 85	UNIT				
	(INPUT)		MIN	TYP	MAX	MIN	MAX			
				5 pF	1.8	2.3	3.1	0.5	6	
±		V	10 pF	2.2	2.8	3.5	1	7.1	~~	
t _{pd}	A, B, or C	ř	15 pF	2.6	3.2	5.2	1	7.9	ns	
		30 pF	3.7	4.4	5.2	1.5	10			

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$, $V_1 = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	PARAMETER FROM TO CL CL	T _A = 25°C			T _A = to 85	UNIT			
	(INPUT)	(001901)		MIN	N TYP MAX MI	MIN	MAX		
			5 pF	2	2.7	3.5	0.5	5.5	
		~	10 pF	2.4	3.1	3.9	1	6.5	
t _{pd}	A, B, or C	Ŷ	15 pF	2.8	3.5	4.3	1	7.4	ns
		30 pF	4	4.7	5.5	1.5	9.5		

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_I = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	PARAMETER	FROM	FROM TO (INPUT) (OUTPUT)		CL	Τ,	∖ = 25°C		T _A = to 85	40°C 5°C	UNIT
		(001901)		_	MIN	TYP	MAX	MIN	MAX		
		, v	5 pF	1.6	2	2.5	0.5	8			
			V	V	V	10 pF	2	2.4	2.9	1	8.5
t _{pd}	A, B, or C	ř	15 pF	2.3	2.8	3.3	1	9.1	ns		
			30 pF	3.4	3.9	4.4	1.5	9.8			

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_I = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	FROM TO CL	T _A = 25°C			T _A = to 85	UNIT		
	(INPUT)	(001901)	-	MIN	TYP	MAX	MIN	MAX	
			5 pF	1.6	1.9	2.4	0.5	5.3	
		V	10 pF	2	2.3	2.7	1	6.1	
^L pd	A, B, or C	ř	15 pF	2.3	2.7	3.1	1	6.8	ns
			30 pF	3.4	3.8	4.2	1.5	8.5	L .



SCES613I-OCTOBER 2004-REVISED MAY 2010

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_1 = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 12)

PARAMETER	FROM	TO	CL	Т	ק = 25°C		T _A = -40°C to 85°C		UNIT	
	(INPUT)	(OUTPUT)	_	MIN	TYP	MAX	MIN	MAX		
t _{pd}	A, B, or C	Y	5 pF	1.6	2.1	2.7	0.5	4.7		
			Y	10 pF	2	2.4	3	1	5.7	
				т 	15 pF	2.3	2.7	3.3	1	6.2
			30 pF	3.4	3.8	4.4	1.5	7.8		

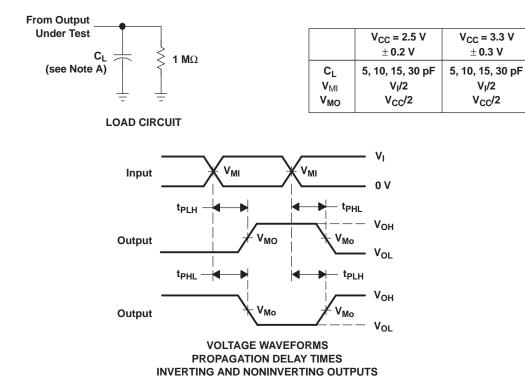
OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC} = 2.5 V	V _{CC} = 3.3 V TYP	UNIT
0	Dewer dissipation conscitutes	f 10 MU-		F	~ Г
C _{pd}	Power dissipation capacitance	f = 10 MHz	4	5	pF

SCES613I-OCTOBER 2004-REVISED MAY 2010

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PARAMETER MEASUREMENT INFORMATION

- NOTES: A. C_L includes probe and jig capacitance.
 - B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , slew rate \geq 1 V/ns.
 - C. The outputs are measured one at a time, with one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 12. Load Circuit and Voltage Waveforms



10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AUP1T97DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT4R	Samples
SN74AUP1T97DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HT4F ~ HT4R)	Samples
SN74AUP1T97DBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HT4F ~ HT4R)	Samples
SN74AUP1T97DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(THF ~ THR)	Samples
SN74AUP1T97DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(THF ~ THR)	Samples
SN74AUP1T97DCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(THF ~ THR)	Samples
SN74AUP1T97DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ТН	Samples
SN74AUP1T97DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ТН	Samples
SN74AUP1T97YEPR	OBSOLET	DSBGA	YEP	6		TBD	Call TI	Call TI	-40 to 85		
SN74AUP1T97YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(TH2 ~ THN)	Samples
SN74AUP1T97YZPR	ACTIVE	DSBGA	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(TH2 ~ TH7 ~ THN)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.



PACKAGE OPTION ADDENDUM

10-Jun-2014

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



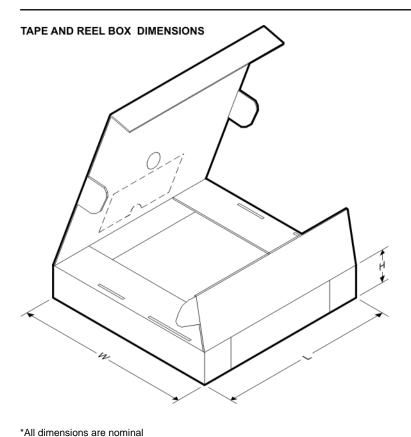
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1T97DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1T97DBVT	SOT-23	DBV	6	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1T97DCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.52	1.2	4.0	8.0	Q3
SN74AUP1T97DCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
SN74AUP1T97DRYR	SON	DRY	6	5000	180.0	8.4	1.25	1.6	0.7	4.0	8.0	Q1
SN74AUP1T97DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.63	4.0	8.0	Q2
SN74AUP1T97YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1
SN74AUP1T97YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

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PACKAGE MATERIALS INFORMATION

22-Oct-2014



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1T97DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74AUP1T97DBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
SN74AUP1T97DCKR	SC70	DCK	6	3000	214.0	199.0	55.0
SN74AUP1T97DCKR	SC70	DCK	6	3000	202.0	201.0	28.0
SN74AUP1T97DRYR	SON	DRY	6	5000	202.0	201.0	28.0
SN74AUP1T97DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74AUP1T97YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0
SN74AUP1T97YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
 - A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
 - E Falls within JEDEC MO-178 Variation AB, except minimum lead width.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



MECHANICAL DATA



- C. SON (Small Outline No-Lead) package configuration.
- Δ The exposed lead frame feature on side of package may or may not be present due to alternative lead frame designs.
- E. This package complies to JEDEC MO-287 variation UFAD.
- 🖄 See the additional figure in the Product Data Sheet for details regarding the pin 1 identifier shape.



DRY (R-PUSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.

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MECHANICAL DATA

PLASTIC SMALL OUTLINE NO-LEAD



NOTES:

DSF (S-PX2SON-N6)

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing Per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration MO-287, variation X2AAF.





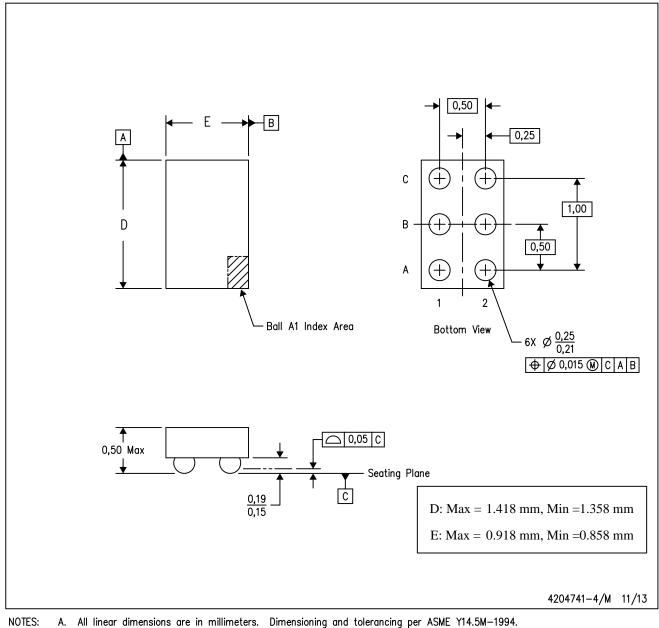
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



YZP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



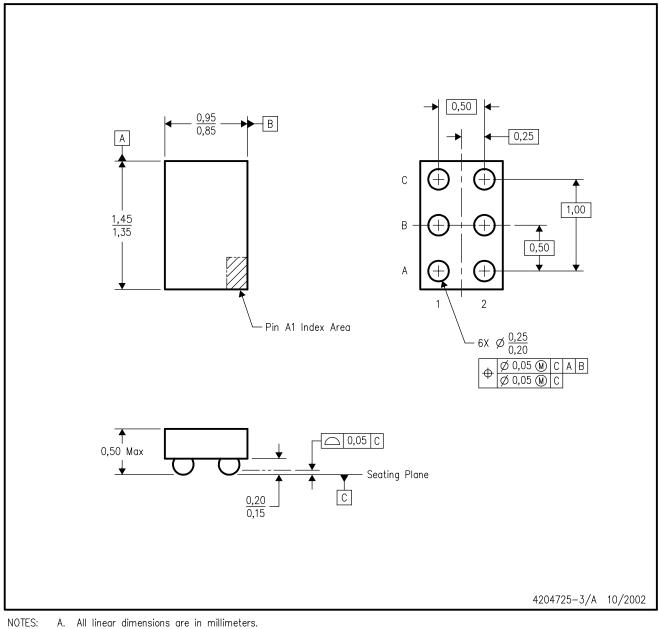
- Α.
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

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YEP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



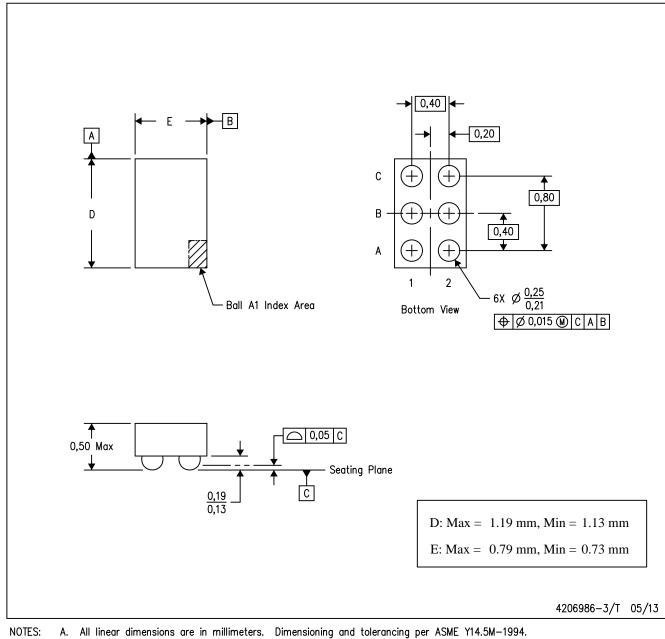
- B. This drawing is subject to change without notice.
- C. NanoStar™ package configuration.
- D. This package is tin-lead (SnPb). Refer to the 6 YZP package (drawing 4204741) for lead-free.

NanoStar is a trademark of Texas Instruments.



YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



B. This drawing is subject to change without notice.

C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments



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